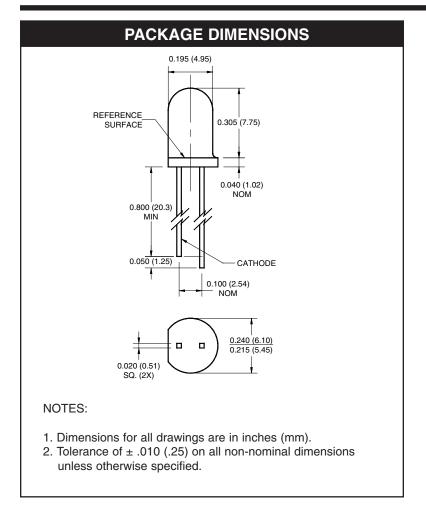
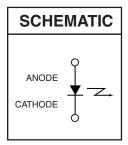
QED233 QED234







DESCRIPTION

The QED233 / QED234 is a 940 nm GaAs / AlGaAs LED encapsulated in a clear untinted, plastic T-1 3/4 package.

FEATURES

- $\lambda = 940 \text{ nm}$
- Chip material =GaAs with AlGaAs window
- Package type: T-1 3/4 (5mm lens diameter)
- Matched Photosensor: QSD122/123/124
- Medium Emission Angle, 40°
- High Output Power
- Package material and color: Clear, untinted, plastic
- · Ideal for remote control applications



QED233 QED234

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)								
Parameter	Symbol	Symbol Rating						
Operating Temperature	T _{OPR}	-40 to +100	°C					
Storage Temperature	T _{STG}	-40 to +100	°C					
Soldering Temperature (Iron)(2,3,4)	T _{SOL-I}	240 for 5 sec	°C					
Soldering Temperature (Flow)(2,3)	T _{SOL-F}	260 for 10 sec	°C					
Continuous Forward Current	I _F	100	mA					
Reverse Voltage	V _R	5	V					
Power Dissipation ⁽¹⁾	P _D	200	mW					
Peak Forward Current	I _{FP}	1.5	A					

- 1. Derate power dissipation linearly 2.67 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6mm) minimum from housing.
- 5. Pulse conditions; $tp = 100 \mu s$, T = 10 ms.

ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C)										
PARAMETER	TEST CONDITIONS	DEVICE	SYMBOL	MIN	TYP	MAX	UNITS			
Peak Emission Wavelength	I _F = 20 mA	ALL	λ_{PE}	_	940	_	nm			
Spectral Bandwidth	I _F = 20 mA	ALL	_	50	_	nm				
Temp. Coefficient of λ_{PE}	I _F = 100 mA	ALL	TC_λ	_	0.2	_	nm/K			
Emission Angle	I _F = 100 mA	ALL	201/ ₂	_	40	_	Deg.			
Forward Voltage	$I_F = 100 \text{ mA}, \text{ tp} = 20 \text{ ms}$	ALL	V _F	_	_	1.6	V			
Temp. Coefficient of V _F	I _F = 100 mA	ALL	TC _∨	_	-1.5	_	mV/K			
Reverse Current	V _R = 5 V	ALL	I _R	_	_	10	μΑ			
Radiant Intensity	I _F = 100 mA, tp = 20 ms	QED233	I _E	10	_	50	mW/sr			
		QED234		27	_	_				
Temp. Coefficient of I _E	I _F = 20 mA	ALL	TCı	_	-0.6	_	%/K			
Rise Time	I _E = 100 mA	ALL	t _r	_	1000	_	. ns			
Fall Time	1 _F = 100 Hi/t	ALL	t _f	_	1000	_				



QED233 QED234

TYPICAL PERFORMANCE CURVES TBD

Fig. 1 Normalized Radiant Intensity vs. Forward Current

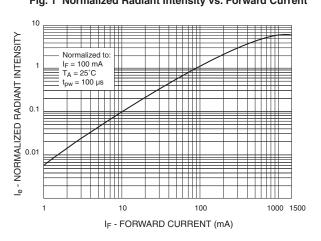


Fig. 2 Forward Voltage Vs. Ambient Temperature

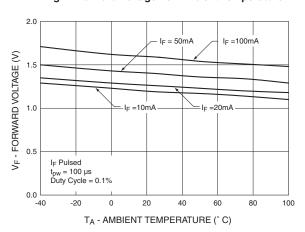


Fig. 3 Normalized Radiant Intensity vs. Wavelength

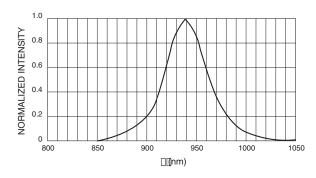


Fig. 4 Radiation Diagram

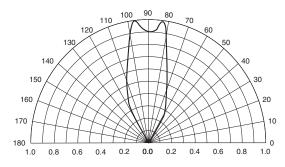
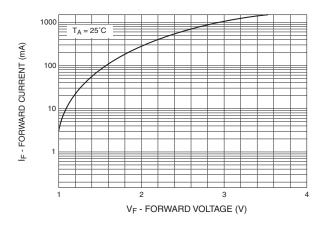


Fig. 5 Forward Current vs. Forward Voltage





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